EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	polyscrystalline adj silicon with laser with irradiat$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L2	1416	polycrystalline adj silicon with laser with irradiat$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L3	0	(polycrystalline or polysilicon) with laser with irradiat$4 with closest	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L4	2	(polycrystalline or polysilicon) with laser with irradiat$4 with grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L5	2	(polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L6	5	(polycrystalline or polysilicon) with laser with irradiat$4 same hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L7	6003	(polycrystalline or polysilicon) with laser with irradiat$4 ansd hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L8	14	(polycrystalline or polysilicon) with laser with irradiat$4 and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12

L9	440	257/64.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L10	2384	257/79.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L11	3146	257/72.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L12	606	257/755.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L13	4	L9 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L14	1	L10 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L15	2	L11 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L16	1	L12 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L17	0	L9 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12

L18	0	L10 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L19	0	L11 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L20	0	L12 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L21	0	polyscrystalline adj silicon with laser with irradiat$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L22	1416	polycrystalline adj silicon with laser with irradiat$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L23	0	(polycrystalline or polysilicon) with laser with irradiat$4 with closest	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L24	2	(polycrystalline or polysilicon) with laser with irradiat$4 with grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L25	2	(polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L26	5	(polycrystalline or polysilicon) with laser with irradiat$4 same hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12

L27	6003	(polycrystalline or polysilicon) with laser with irradiat$4 ansd hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L28	14	(polycrystalline or polysilicon) with laser with irradiat$4 and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L29	440	257/64.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L30	2384	257/79.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L31	3146	257/72.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L32	606	257/755.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L33	4	L29 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L34	1	L30 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L35	2	L31 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12

L36	1	L32 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L37	0	L29 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L38	0	L30 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L39	0	L31 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L40	0	L32 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L41	12225	L21 L22 L23 L24 L25 L26 L27 L28 L29 L30 L31 L32 L33 L34 L35 L36 L37 L38 L39 L40	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L42	30	("20010046755" | "20040173800" | "20050142452" | "20050271952" | "20050285120" | "20060102901" | "5581102" | "5714404" | "5893730" | "5915180" | "6096434" | "6172380" | "6172380" | "6287944" | "6493127" | "6566754" | "6649824").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12

L43	5	L26 and (polycrystalline or polysilicon) with laser with irradiat$4 same hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L44	20	closest with grain with "6"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L45	9	L44 and laser	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L46	5	L45 and semiconductor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L47	0	closest adj crystal adj grain with "6"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
L48	12250	L1 L2 L3 L4 L5 L6 L7 L8 L9 L10 L11 L12 L13 L14 L15 L16 L17 L18 L19 L20 L21 L22 L23 L24 L25 L26 L27 L28 L29 L30 L31 L32 L33 L34 L35 L36 L37 L38 L39 L40 L41 L42 L43 L44 L45 L46 L47	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/28 21:12
S1	0	polycrystalline adj silicon with laser with irradiat$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:31
S2	1173	polycrystalline adj silicon with laser with irradiat$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:31

S3	0	(polycrystalline or polysilicon) with laser with irradiat$4 with closest	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:31
S4	1	(polycrystalline or polysilicon) with laser with irradiat$4 with grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:32
S5	1	(polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:41
S6	1	(polycrystalline or polysilicon) with laser with irradiat$4 same hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:35
S7	5125	(polycrystalline or polysilicon) with laser with irradiat$4 ansd hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:35
S8	8	(polycrystalline or polysilicon) with laser with irradiat$4 and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:38
S9	383	257/64.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:38
S10	1836	257/79.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:38
S11	2439	257/72.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:38

S12	590	257/755.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:38
S13	2	S9 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:39
S14	1	S10 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:38
S15	1	S11 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:39
S16	1	S12 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:39
S17	0	S9 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:41
S18	0	S10 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:41
S19	0	S11 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:41
S20	0	S12 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/10 19:41

S21	0	polyscrystalline adj silicon with laser with irradiat$4...	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S22	1416	polycrystalline adj silicon with laser with irradiat$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S23	0	(polycrystalline or polysilicon) with laser with irradiat$4 with closest	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S24	2	(polycrystalline or polysilicon) with laser with irradiat$4 with grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S25	2	(polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S26	5	(polycrystalline or polysilicon) with laser with irradiat$4 same hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S27	6002	(polycrystalline or polysilicon) with laser with irradiat$4 ansd hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S28	14	(polycrystalline or polysilicon) with laser with irradiat$4 and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S29	440	257/64.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59

S30	2384	257/79.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S31	3146	257/72.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S32	606	257/755.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S33	4	S29 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S34	1	S30 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S35	2	S31 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S36	1	S32 and (polycrystalline or polysilicon) with laser and hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S37	0	S29 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S38	0	S30 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59

S39	0	S31 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S40	0	S32 and (polycrystalline or polysilicon) with laser with irradiat$4 same grains with six	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S41	12224	S21 S22 S23 S24 S25 S26 S27 S28 S29 S30 S31 S32 S33 S34 S35 S36 S37 S38 S39 S40	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 20:59
S42	30	("20010046755" | "20040173800" | "20050142452" | "20050271952" | "20050285120" | "20060102901" | "5581102" | "5714404" | "5893730" | "5915180" | "6096434" | "6172380" | "6172380" | "6287944" | "6493127" | "6566754" | "6649824").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 21:02
S43	5	S26 and (polycrystalline or polysilicon) with laser with irradiat$4 same hexagon$6 with grain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 21:03
S44	20	closest with grain with "6"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 21:58
S45	9	S44 and laser	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/27 21:58

| S46 | 5 | S45 and semiconductor | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2008/09/27 21:58 |
| S47 | 0 | closest adj crystal adj grain with "6" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2008/09/28 14:58 |

9/28/08 10:14:57 PM
C:\Documents and Settings\LSchillinger\My Documents\EAST\Workspaces\10019407.wsp